

ZXTN25040DFL 40V, SOT23, NPN low power transistor

Summary

 $BV_{CEX} > 130V$ $BV_{CEO} > 40V$ $BV_{ECO} > 6V$ $I_{C(cont)} = 1.5A$ $V_{CE(sat)} < 85mV @ 1A$ $R_{CE(sat)} = 59m\Omega$ $P_{D} = 350mW$



Complementary part number ZXTP25040DFL

Description

Advanced process capability has been used to achieve high current gain hold up making this device ideal for applications requiring high pulse currents.

Features

- High peak current
- Low saturation voltage
- 130V forward blocking voltage
- 6V reverse blocking voltage

Applications

- MOSFET and IGBT gate driving
- DC-DC conversion
- LED driving
- · Interface between low voltage IC's and loads

Ordering information

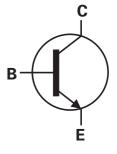
loads		E
		Pinout - top view
Tape width	Quantity per reel]

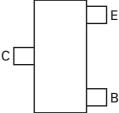
Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25040DFLTA	7	8	3000

Device marking

1B7







Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V _{CBO}	130	V
Collector-emitter voltage (forward blocking)	V _{CEX}	130	V
Collector-emitter voltage	V _{CEO}	40	V
Emitter-collector voltage (reverse blocking)	V _{ECO}	6	V
Emitter-base voltage	V _{EBO}	7	V
Continuous collector current ^(a)	۱ _C	1.5	А
Base current	Ι _Β	0.5	А
Peak pulse current	I _{СМ}	6	А
Power dissipation at $T_{amb} = 25^{\circ}C^{(a)}$	P _D	350	mW
Linear derating factor		2.8	mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C

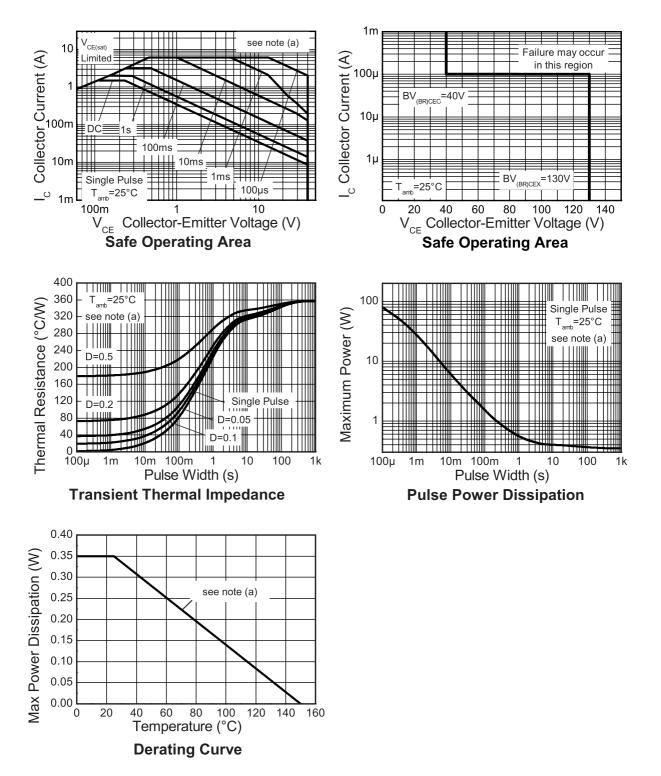
Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	R_{\ThetaJA}	357	°C/W

NOTES:

(a) For a device surface mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

Characteristics



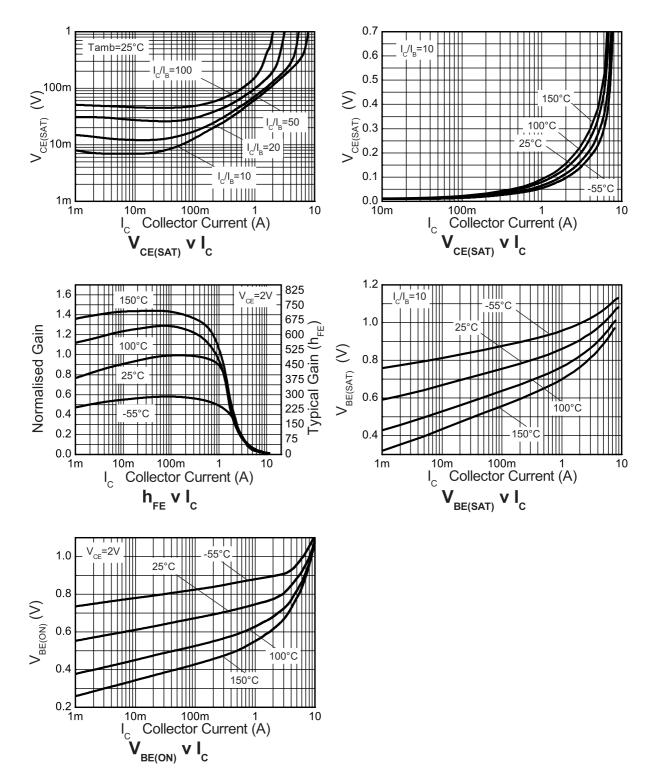
Electrical characteristics	(at T _{am}	b = 25°	°C unless	otherwi	se stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CBO}	130	170		V	I _C = 100μA
Collector-emitter breakdown voltage (forward blocking)	BV _{CEX}	130	170		V	I_C = 100μA; R_{BE} < 1kΩ or -1V < V_{BE} < 0.25V
Collector-emitter breakdown voltage (base open)	BV _{CEO}	40	63		V	I _C = 10mA ^(*)
Emitter-base breakdown voltage	BV _{EBO}	7	8.3		V	I _E = 100μA
Emitter-collector breakdown voltage (reverse blocking)	BV _{ECX}	6	7.4		V	I_{E} = 100μA, R_{BC} < 1kΩ or 0.25V > V_{BC} > -0.25V
Emitter-collector breakdown voltage (base open)	BV _{ECO}	6	7.4		V	I _E = 100μA,
Collector cut-off current	I _{CBO}		<1	50 20	-	V _{CB} = 100V V _{CB} = 100V, T _{amb} = 100°C
Collector emitter cut-off current	I _{CEX}		<1	100	nA	V_{CE} = 100V; R_{BE} < 1k Ω or -1V < V_{BE} < 0.25V
Emitter cut-off current	I _{EBO}		<1	50	nA	V _{EB} = 5.6V
Collector-emitter saturation	V _{CE(sat)}		35	50	mV	I _C = 0.5A, I _B = 50mA ^(*)
voltage			60	80	mV	l _C = 0.5A, l _B = 10mA ^(*)
			70	85	mV	I _C = 1A, I _B = 100mA
			145	185	mV	l _C = 1.5A, l _B = 30mA ^(*)
			235	285	mV	I _C = 4A, I _B = 400mA ^(*)
Base-emitter saturation voltage	V _{BE(sat)}		840	950	mV	I _C = 1.5A, I _B = 30mA ^(*)
Base-emitter turn-on voltage	V _{BE(on)}		770	850	mV	$I_{C} = 1.5A, V_{CE} = 2V^{(*)}$
Static forward current	h _{FE}	300	450	900		$I_{C} = 10 \text{mA}, V_{CE} = 2V^{(*)}$
transfer ratio		300	400			$I_{C} = 1A, V_{CE} = 2V^{(*)}$
		170	250			I _C = 1.5A, V _{CE} = 2V ^(*)
		25	40			$I_{C} = 4A, V_{CE} = 2V^{(*)}$
Transition frequency	f _T		190		MHz	$I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
Output capacitance	C _{obo}		11.7	20	pF	V _{CB} = 10V, f = 1MHz ^(*)
Delay time	t _(d)		64		ns	V _{CC} = 10V,
Rise time	t _(r)		108		ns	I _C = 1A,
Storage time	t _(s)		428		ns	I _{B1} = I _{B2} = 10mA.
Fall time	t _(f)		130		ns	1

NOTES:

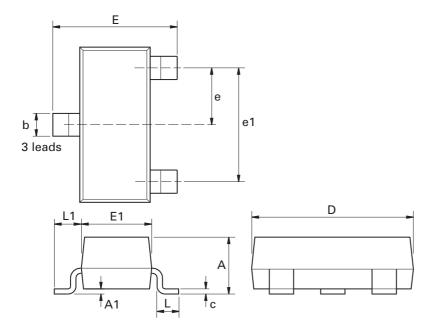
(*) Measured under pulsed conditions. Pulse width \leq 300µs; duty cycle \leq 2%.

Typical characteristics



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Package outline - SOT23



Dim.	Millin	neters	Inc	hes	Dim.	Dim. Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	1.12	-	0.044	e1	1.90	NOM	0.075	NOM
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95	NOM	0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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